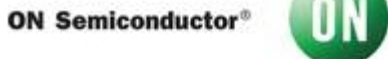




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|---|---|
|  | <p>Hersteller-Teilenummer: NTD4809NT4G</p> |
| | <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> |
|  | <p>Teil der Beschreibung: MOSFET N-CH 30V 9.6A DPAK</p> |
| | <p>Datenblätter:  NTD4809NT4G.pdf</p> |
| | <p>RoHs Status: Bleifrei / RoHS-konform</p> |
| | <p>Lagerzustand: New original, 119453 pcs Stock Available.</p> |
| | <p>Liefern von: Hong Kong</p> |
| <p>Image may be representation. See specs for product details.</p> | <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |

Spezifikationen

| | |
|---|---|
| Teilenummer | NTD4809NT4G |
| Hersteller | AMI Semiconductor / ON Semiconductor |
| Beschreibung | MOSFET N-CH 30V 9.6A DPAK |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 119453 pcs Stock |
| Serie | - |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 175°C (TJ) |
| Befestigungsart | Surface Mount |
| Verpackung / Gehäuse | TO-252-3, DPak (2 Leads + Tab), SC-63 |
| Supplier Device-Gehäuse | DPAK |
| Verlustleistung (max) | 1.4W (Ta), 52W (Tc) |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 30V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 °C | 9.6A (Ta), 58A (Tc) |
| Rds On (Max) @ Id, Vgs | 9 mOhm @ 30A, 10V |
| VGS (th) (Max) @ Id | 2.5V @ 250µA |
| Gate Charge (Qg) (Max) @ Vgs | 25nC @ 11.5V |
| Eingabekapazität (Ciss) (Max) @ Vds | 1456pF @ 12V |
| Antriebsspannung (Max Rds On, Min Rds On) | 4.5V, 11.5V |
| Vgs (Max) | ±20V |
| Verpackung | Tape & Reel (TR) |


















































NTD4809NT4G ist neu im Original, Suche NTD4809NT4G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD4809NT4G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD4809NT4G: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|--|---|--|--|
|  <p>NTD4809NHG ON NTD4809NHG ON</p> |  <p>NTD4809NHT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 9A DPAK</p> |  <p>NTD4810N-35G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 8.6A IPAK</p> |  <p>NTD4810N ON NTD4810N ON</p> |
|  <p>NTD4809NH-35G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 9A IPAK</p> |  <p>NTD4810NG ON NTD4810NG ON</p> |  <p>NTD4809NH ON ON TO-252</p> |  <p>NTD4810N-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 8.6A IPAK</p> |

heiße Teile

Mehr

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Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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